

Session Program

4-6 Jun 2007

10th RD50 Workshop

Pad Detector Characterization II

Vilnius, Lithuania

Tuesday 5 June

09:00

Pad Detector Characterization II

Session | Location: Vilnius, Lithuania

09:00–09:20

Determination of the Charge Collection Efficiency in irradiated Silicon Detectors

Speaker

Hartmut Sadrozinski

09:40–10:00

Systematic Simulations of Charge Collection in Planar (2D) and 3D Si detectors at Various Fluences and Thicknesses

Speaker

Zheng Li

10:00–10:20

Extraction of the doping density of irradiated silicon detectors using C-V data

Speaker

Hartmut Sadrozinski

10:20–10:50

coffee break

10:50–11:10

Discussion Session - Simulation of Pad detectors

11:10